2SK0665 (2SK665)

Silicon N-Channel MOS FET

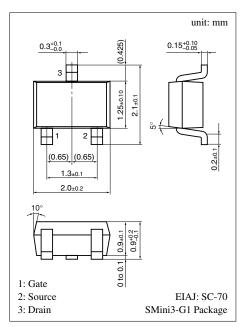
For switching

■ Features

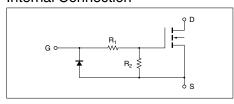
- High-speed switching
- Small drive current owing to high input inpedance
- High electrostatic breakdown voltage

■ Absolute Maximum Ratings (Ta = 25°C)

| Parameter | Symbol | Ratings | Unit | |
|-----------------------------|------------------|-------------|------|--|
| Drain to Source voltage | V _{DS} | 20 | V | |
| Gate to Source voltage | V_{GSO} | 8 | V | |
| Drain current | I_D | 100 | mA | |
| Max drain current | I_{DP} | 200 | mA | |
| Allowable power dissipation | P_{D} | 150 | mW | |
| Channel temperature | T _{ch} | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |



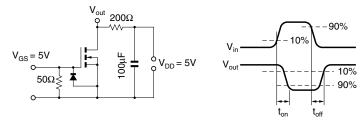
Marking Symbol: 30 Internal Connection



■ Electrical Characteristics (Ta = 25°C)

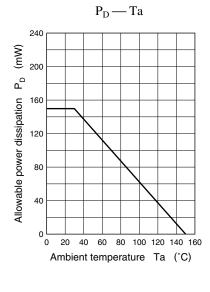
| Parameter | Symbol | Conditions | min | typ | max | Unit |
|-----------------------------------|------------------------|---|-----|-----|-----|------|
| Drain to Source cut-off current | I_{DSS} | $V_{DS} = 10V, V_{GS} = 0$ | | | 10 | μA |
| Gate to Source leakage current | I_{GSS} | $V_{GS} = 8V, V_{DS} = 0$ | 40 | | 80 | μΑ |
| Drain to Source breakdown voltage | V _{DSS} | $I_D = 100 \mu A, V_{GS} = 0$ | 20 | | | V |
| Gate threshold voltage | V_{th} | $I_D = 100\mu A, V_{DS} = V_{GS}$ | 1.5 | | 3.5 | V |
| Drain to Source ON-resistance | R _{DS(on)} *3 | $I_D = 20$ mA, $V_{GS} = 5$ V | | | 50 | Ω |
| Forward transfer admittance | Y _{fs} | $I_D = 20 \text{mA}, V_{DS} = 5 \text{V}, f = 1 \text{kHz}$ | 20 | | | mS |
| High level output voltage | V _{OH} | $V_{DD} = 5V, V_{GS} = 1V, R_{L} = 200\Omega$ | 4.5 | | | V |
| Low level output voltage | V_{SL} | $V_{DD} = 5V, V_{GS} = 5V, R_{L} = 200\Omega$ | | | 1 | V |
| Input resistance | $R_1 + R_2^{*1}$ | | 100 | | 200 | kΩ |
| Turn-on time | t _{on} *2 | $V_{DD} = 5V$, $V_{GS} = 0$ to $5V$, $R_L = 200\Omega$ | | | 1 | μs |
| Turn-off time | t _{off} *2 | $V_{DD} = 5V$, $V_{GS} = 5$ to $0V$, $R_{L} = 200\Omega$ | | | 1 | μs |

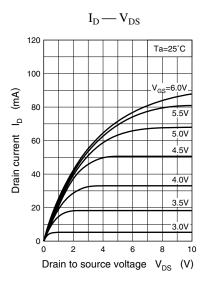
 $^{^{*1}}$ Resistance ratio $R_1/R_2 = 1/50$ *2 t_{on} , t_{off} measurement circuit *3 Pulse measurement

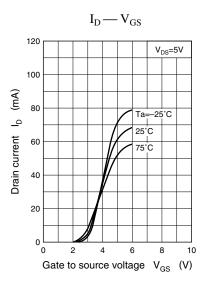


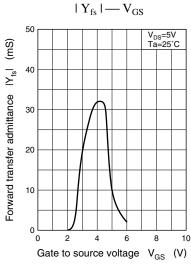
Note) The part number in the parenthesis shows conventional part number.

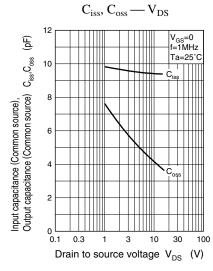
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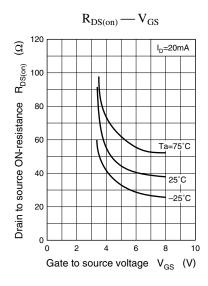


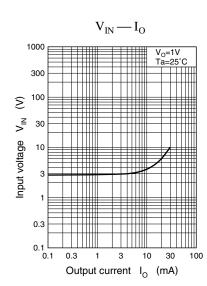












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